

## 2SB1494

Silicon PNP Triple Diffused  
Low Frequency Power Amplifier  
Complementary Pair with 2SD2256

### Feature

- High Voltage and High Current  
( $V_{CE0} = -120\text{ V}$ ,  $I_C = -25\text{ A}$ )
- Built-in C-E diode

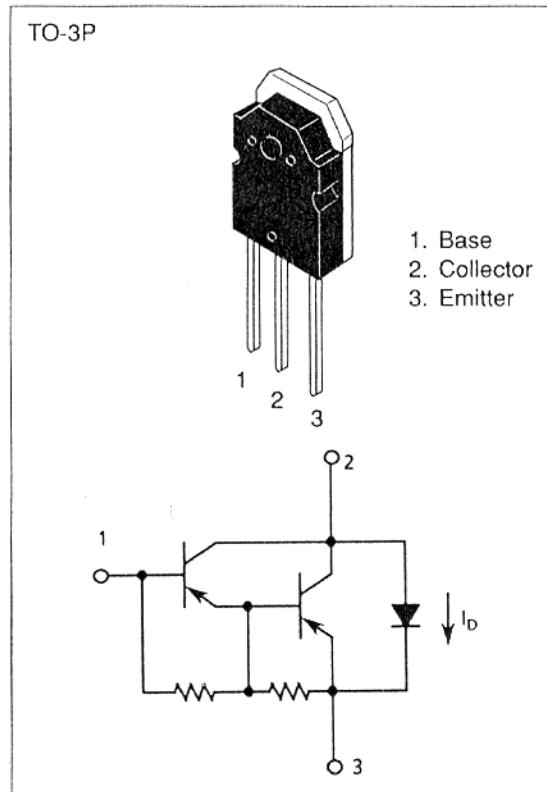
### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Rating	Unit
Collector to base voltage	$V_{CB0}$	-120	V
Collector to emitter voltage	$V_{CE0}$	-120	V
Emitter to base voltage	$V_{EBO}$	-7	V
Collector current	$I_C$	-25	A
Collector peak current	$i_{C(\text{peak})}$	-35	A
Collector power dissipation	$P_C^{*1}$	120	W
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{\text{stg}}$	-55 to +150	$^\circ\text{C}$
C to E diode forward current	$I_D^{*1}$	25	A

Note: 1. Value at  $T_C = 25^\circ\text{C}$ .

### Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

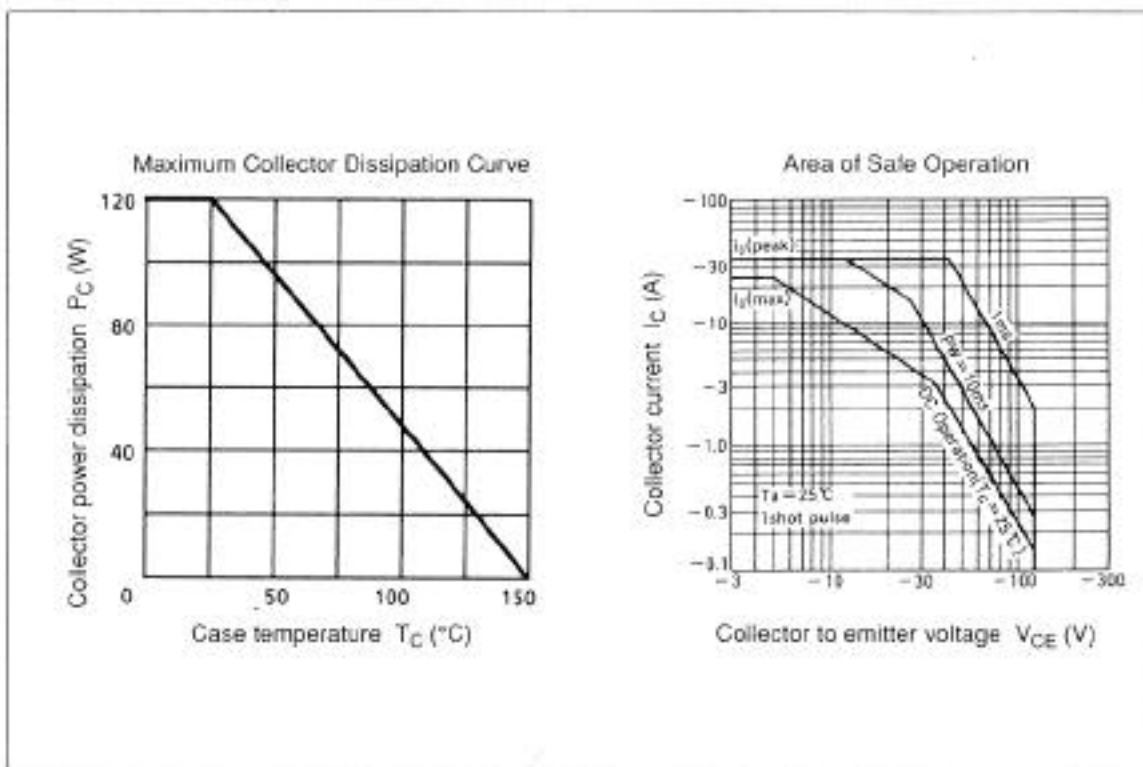
Item	Symbol	Min	Typ	Max	Unit	Test condition
Collector to base breakdown voltage	$V_{(BR)CB0}$	-120	—	—	V	$I_C = -0.1\text{ mA}$ , $I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CE0}$	-120	—	—	V	$I_C = -25\text{ mA}$ , $R_{BE} = \infty$
Collector to emitter sustain voltage	$V_{CE0(\text{SUS})}$	-120	—	—	V	$I_C = -200\text{ mA}$ , $R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-7	—	—	V	$I_E = -50\text{ mA}$ , $I_C = 0$
Collector cutoff current	$I_{CB0}$	—	—	-10	$\mu\text{A}$	$V_{CB} = -100\text{ V}$ , $I_E = 0$
	$I_{CE0}$	—	—	-10		$V_{CE} = -100\text{ V}$ , $R_{BE} = \infty$
DC current transfer ratio	$h_{FE1}$	2000	—	20000		$V_{CE} = -4\text{ V}$ , $I_C = -12\text{ A}^{*1}$
	$h_{FE2}$	500	—	—		$V_{CE} = -4\text{ V}$ , $I_C = -25\text{ A}^{*1}$



### Electrical Characteristics (Ta = 25°C) (cont)

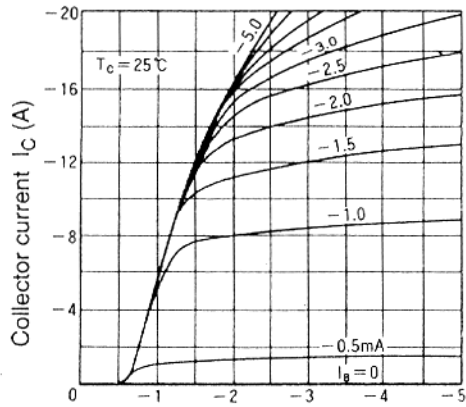
Item	Symbol	Min	Typ	Max	Unit	Test condition
Collector to emitter saturation voltage	$V_{CE(sat)1}$	—	—	-2.0	V	$I_C = -12\text{ A}, I_B = -24\text{ mA}^{*1}$
	$V_{CE(sat)2}$	—	—	-3.5		$I_C = -25\text{ A}, I_B = -250\text{ mA}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)1}$	—	—	-3.0	V	$I_C = -12\text{ A}, I_B = -24\text{ mA}$
	$V_{BE(sat)2}$	—	—	-4.5		$I_C = -25\text{ A}, I_B = -250\text{ mA}^{*1}$

Note: 1. Pulse Test.



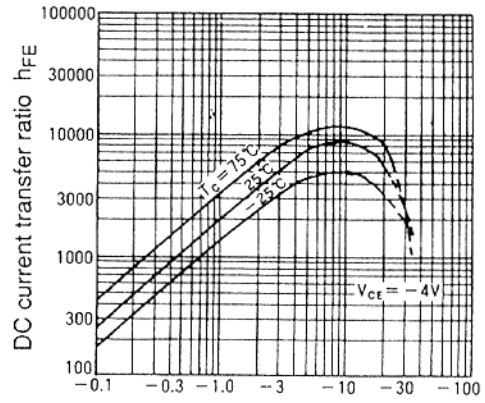
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Typical Output Characteristics



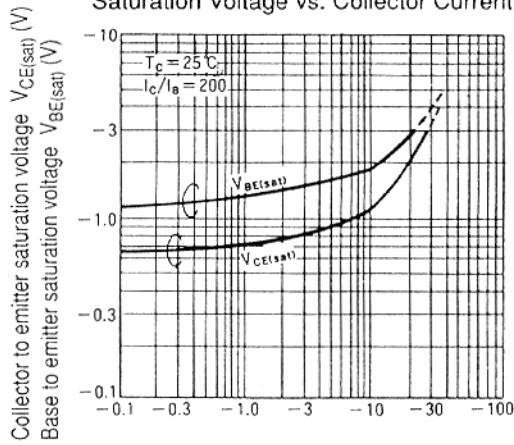
Collector to emitter voltage  $V_{CE}$  (V)

DC Current Transfer Ratio vs. Collector Current



Collector current  $I_C$  (A)

Saturation Voltage vs. Collector Current



Collector current  $I_C$  (A)

